



Response Under 37 CFR § 1.116  
Expedited Procedure

501.42841X00

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IPW

**IN THE UNITED STATES PATENT AND TRADEMARK OFFICE**

Applicant(s): KUMAGAI, et al.  
Serial No.: 10/625,616  
Filed: July 24, 2003  
For: SEMICONDUCTOR DEVICE INCLUDING N-CHANNELED  
FETs AND P-CHANNELED FETs WITH IMPROVED DRAIN  
CURRENT CHARACTERISTICS (*As Amended*)  
Group: 2811 Exr. H. Vu

**AMENDMENT AFTER FINAL**

**MS: AFTER FINAL**  
Commissioner of Patents  
POB 1450  
Alexandria, VA 22313-1450

Jan. 18, 2006

Sir:

In response to the Final Office Action dated October 18, 2005, please amend  
the above-identified application as listed below and as set forth on the following  
pages:

**Amendments to the Claims; and**

**Remarks are included following the amendments.**

OK  
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